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ELECTRONICS

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Jameco Part Number 1524762

TCRT5000L



Reflective Optical Sensor with Transistor Output

Description

The TCRT5000 and TCRT500L are reflective sensors which include an infrared emitter and phototransistor in a leaded package which blocks visible light. The package includes two mounting clips. TCRT5000L is the long lead version.

Features

· Package type: Leaded

· Detector type: Phototransistor

• Dimensions:

L 10.2 mm x W 5.8 mm x H 7.0 mm

Peak operating distance: 2.5 mmOperating range: 0.2 mm to 15 mm

Typical output current under test: I_C = 1 mA

· Daylight blocking filter

• Emitter wavelength 950 nm

· Lead (Pb)-free soldering released

 Lead (Pb)-free component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC





Applications

TCRT5000

Position sensor for shaft encoder

Top view

- Detection of reflective material such as paper, IBM cards, magnetic tapes etc.
- Limit switch for mechanical motions in VCR
- · General purpose wherever the space is limited

Order Instructions

Part Number	Remarks	Minimum Order Quantity	
TCRT5000	3.5 mm lead length	4500 pcs, 50 pcs/tube	
TCRT5000L	15 mm lead length	2400 pcs, 48 pcs/tube	

Absolute Maximum Ratings

 T_{amb} = 25 °C, unless otherwise specified

Input (Emitter)

Parameter	Test condition	Symbol	Value	Unit
Reverse voltage		V_{R}	5	٧
Forward current		I _F	60	mA
Forward surge current	$t_p \le 10 \ \mu s$	I _{FSM}	3	Α
Power dissipation	T _{amb} ≤ 25 °C	P _V	100	mW
Junction temperature		T _j	100	°C

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Output (Detector)

Parameter	Test condition	Symbol	Value	Unit
Collector emitter voltage		V_{CEO}	70	V
Emitter collector voltage		V _{ECO}	5	V
Collector current		I _C	100	mA
Power dissipation	T _{amb} ≤ 55 °C	P_V	100	mW
Junction temperature		T_j	100	°C

Sensor

Parameter	Test condition	Symbol	Value	Unit
Total power dissipation	T _{amb} ≤ 25 °C	P _{tot}	200	mW
Operation temperature range		T _{amb}	- 25 to + 85	°C
Storage temperature range		T _{stg}	- 25 to + 100	°C
Soldering temperature	2 mm from case, $t \le 10 \text{ s}$	T _{sd}	260	°C

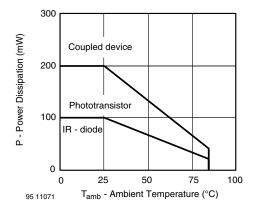


Figure 1. Power Dissipation Limit vs. Ambient Temperature

Electrical Characteristics

 T_{amb} = 25 °C, unless otherwise specified

Input (Emitter)

Parameter	Test condition	Symbol	Min	Тур.	Max	Unit
Forward voltage	I _F = 60 mA	V _F		1.25	1.5	V
Junction capacitance	$V_R = 0 V, f = 1 MHz$	C _j		17		pF
Radiant intensity	$I_F = 60 \text{ mA}, t_P = 20 \text{ ms}$	Ι _Ε			21	mW/sr
Peak wavelength	I _F = 100 mA	λ _P	940			nm
Virtual source diameter	Method: 63 % encircled energy	Ø		2.1		mm

Output (Detector)

Parameter	Test condition	Symbol	Min	Тур.	Max	Unit
Collector emitter voltage	I _C = 1 mA	V_{CEO}	70			V
Emitter collector voltage	I _E = 100 μA	V _{ECO}	7			V
Collector dark current	$V_{CE} = 20 \text{ V}, I_F = 0, E = 0$	I _{CEO}		10	200	nA



Sensor

Parameter	Test condition	Symbol	Min	Тур.	Max	Unit
Collector current	$V_{CE} = 5 \text{ V, } I_F = 10 \text{ mA,}$ D = 12 mm	I _C ^{1,2)}	0.5	1	2.1	mA
	I _F = 10 mA, I _C = 0.1 mA, D = 12 mm	V _{CEsat} 1,2)			0.4	V

¹⁾ See figure 3

²⁾ Test surface: Mirror (Mfr. Spindler a. Hoyer, Part No 340005)

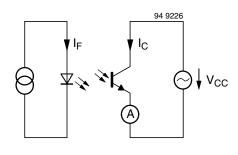


Figure 2. Test Circuit

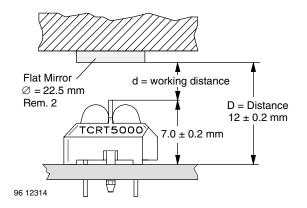


Figure 3. Test Circuit

Typical Characteristics

T_{amb} = 25 °C, unless otherwise specified

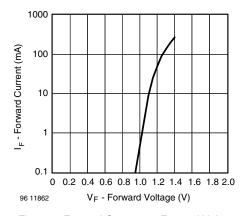


Figure 4. Forward Current vs. Forward Voltage

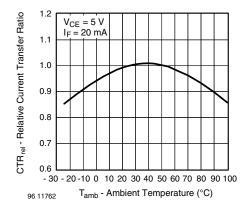


Figure 5. Relative Current Transfer Ratio vs.
Ambient Temperature



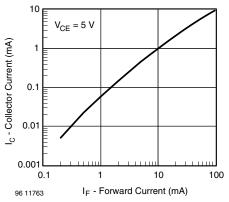


Figure 6. Collector Current vs. Forward Current

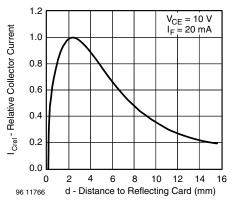


Figure 9. Relative Collector Current vs. Distance

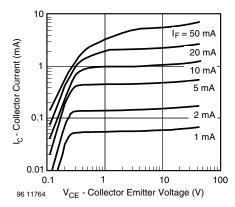


Figure 7. Collector Emitter Saturation Voltage vs. Collector Current

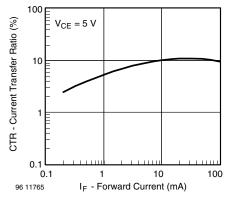
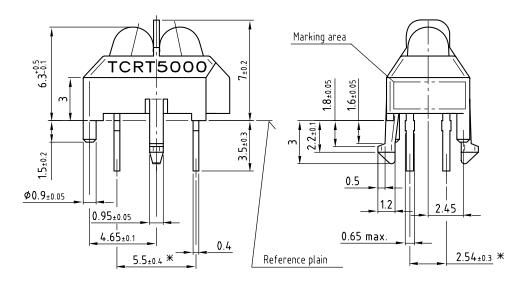
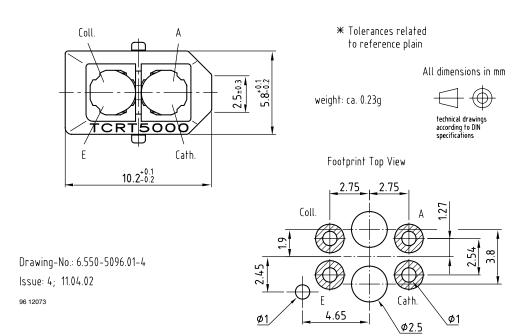


Figure 8. Current Transfer Ratio vs. Forward Current



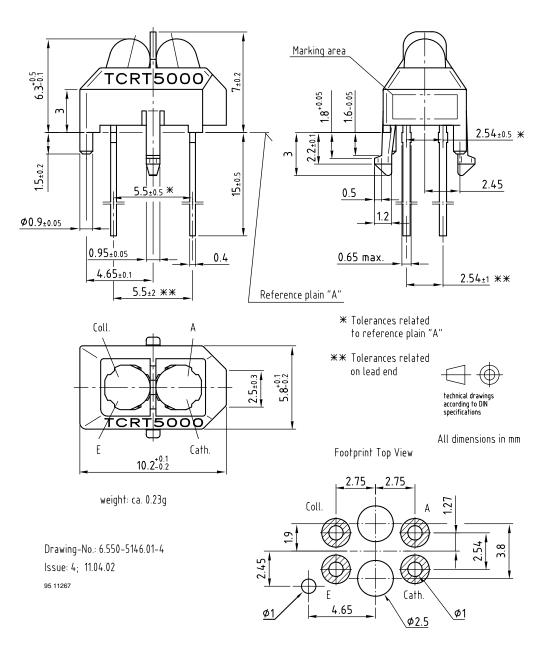
Package Dimensions in mm





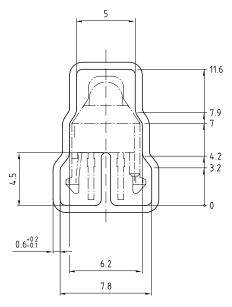
Document Number 83760 Rev. 1.6, 04-Sep-06







TCRT5000, Tube Dimensions

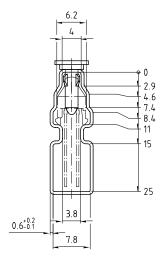


With rubber stopper Tolerance: ±0.5mm Length: 575±1mm All dimensions in mm

Drawing-No.: 9.700-5139.01-4

Issue: 1; 10.05.00

TCRT5000L, Tube Dimensions



With stopper pins Tolerance: ±0.5mm Length: 575±1mm

All dimensions in mm

Drawing-No.: 9.700-5178.01-4 Issue: 1; 25.02.00 ²⁰²⁹⁹

TCRT5000(L)

Vishay Semiconductors



Ozone Depleting Substances Policy Statement

It is the policy of Vishay Semiconductor GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

> We reserve the right to make changes to improve technical design and may do so without further notice.

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